Self-trapped excitons with unusually large Huang-Rhys factor in halide double perovskite semiconductor Cs₂AgInCl₆

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In the search for stable and non-toxic alternatives to single perovskites, lead-free halide double perovskite semiconductors have emerged as a promising class of optoelectronic materials having a common chemical formula $A_2MM'X_6$ with potential applications in photovoltaics and lighting technology [1]. Here, A is a monovalent cation, M and M' are a monovalent and a trivalent metal ion, respectively, and X is a halide ion. These materials possess a soft polar lattice with strong electron-phonon coupling, which favors the formation of self-trapped excitons, leading to broad photoluminescence (PL) spectra. The strength of this coupling is estimated with a dimensionless number called Huang-Rhys factor [2].

Temperature-dependent PL spectra of $Cs_2AgInCl_6$ single crystals under 375 nm excitation show a bright, broad emission centered around 500 nm at temperatures below 150 K. However, above 180 K, the emission shifts to a significantly broader and much less intense peak around 600 nm [Figure 1(a)]. Polarized Raman scattering studies confirm that no global structural phase transition is involved.

Further investigations using temperature- and excitation-power-dependent PL studies indicate that these emissions originate from two distinct excitonic populations, with the 600 nm peak appearing above 90 K. Time-resolved spectral evolution reveals that the 500 nm emission dominates at earlier times, while the 600 nm emission becomes more prominent at later times.

Regular and time-resolved temperature-dependent broadening analysis confirms that the 500 nm peak corresponds to a previously identified self-trapped exciton emission, characterized by a large Huang-Rhys factor (S) of 38 [2]. In contrast, the 600 nm peak exhibits an exceptionally large S value of approximately 400 [Figure 1(c)]. Thermal expansion studies [Figure 1(d)] suggest that, although no phase transition occurs, the unusually strong electron-phonon coupling arises from lattice dynamics.



References

- [1] Y. Liu et al., Angew. Chem. Int. Ed. 60, 11592–11603 (2021).
- [2] J. Luo et al., Nature 563, 541–545 (2018).

Figure 1: (a) Temperature-dependent evolution of the PL spectra of Cs₂AgInCl₆ single crystals under continuous-wave (CW) excitation at 375 nm. (b) Schematic representation of the protocol used to acquire time-resolved PL spectra. The thin green rectangle labeled 'L' represents a 2 ps laser pulse. A charge-coupled device (CCD) camera is exposed for a set duration at varying time delays relative to the laser pulse. This cycle is repeated to accumulate and record PL spectra. (c) Temperature-dependent broadening, $\Gamma(T)$, of the PL spectra, used to estimate the Huang-Rhys factor (S) by fitting with the equation $\Gamma(T) = 2.36 \sqrt{S} \hbar \omega \coth\left(\frac{\hbar \omega}{2k_BT}\right)$. The green triangles correspond to the PL widths from the spectra in (a), while the red circles and blue diamonds represent the widths of time-resolved PL spectra recorded at 26 ns and 15 µs after the laser pulse, respectively. The solid lines indicate fits to the equation. (d) Thermal expansion behavior of Cs2AgInCl6 single crystals.